

# PBSS5360X 60 V, 3 A PNP low VCEsat (BISS) transistor

3 July 2017

Product data sheet

## 1. General description

PNP low V<sub>CEsat</sub> Breakthrough in Smal Signal (BISS) transitor in a medium power SOT89 (SC-62) flat lead Surface-Mounted Device (SMD) plastic package.

NPN complement: PBSS4360X

## 2. Features and benefits

- Low collector-emitter saturation voltage V<sub>CEsat</sub> •
- High collector current capability  $I_{C}$  and  $I_{CM}$ •
- · High energy efficiency due to less heat generation
- AEC-Q101 qualified

## 3. Applications

- DC-to-DC conversion
- Supply line switches
- · Battery charger
- LCD backlighting
- Driver in low supply voltage applications (e.g. lamps and LEDs)
- Inductive load driver (e.g. relays, buzzers and motors)

#### 4. Quick reference data

Table 1. Qui	ck reference data						
Symbol	Parameter	Conditions		Min	Тур	Max	Unit
V <sub>CEO</sub>	collector-emitter voltage	open base		-	-	-60	V
I <sub>C</sub>	collector current			-	-	-3	А
I <sub>CM</sub>	peak collector current	single pulse; $t_p \le 1 \text{ ms}$		-	-	-6	А
R <sub>CEsat</sub>	collector-emitter saturation resistance	$I_{C}$ = -2 A; $I_{B}$ = -200 mA; $T_{amb}$ = 25 °C	[1]	-	-	225	mΩ

[1] Pulse test:  $t_p \le 300 \ \mu s$ ;  $\delta \le 0.02$ 

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## 5. Pinning information

Table 2. Pinning information								
Pin	Symbol	Description	Simplified outline	Graphic symbol				
1	E	emitter		C				
2	С	collector		вщ				
3	В	base	3 2 1 SOT89	E sym132				

## 6. Ordering information

Table 3. Ordering information						
Type number	Package	2				
	Name	Description	Version			
PBSS5360X	SOT89	plastic, surface-mounted package; 3 leads; 1.5 mm pitch; 4.5 mm x 2.5 mm x 1.5 mm body	SOT89			

## 7. Marking

Table 4. Marking codes	
Type number	Marking code
PBSS5360X	S42

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## 8. Limiting values

#### Table 5. Limiting values

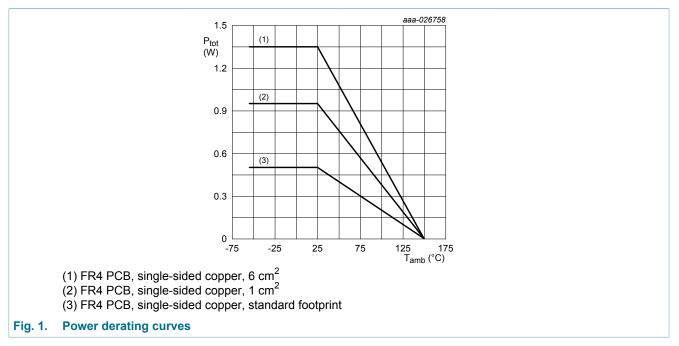
In accordance with the Absolute Maximum Rating System (IEC 60134)

Symbol	Parameter	Conditions		Min	Мах	Unit
V <sub>CBO</sub>	collector-base voltage	open emitter		-	-80	V
V <sub>CEO</sub>	collector-emitter voltage	open base		-	-60	V
V <sub>EBO</sub>	emitter-base voltage	open collector		-	-7	V
I <sub>C</sub>	collector current			-	-3	А
I <sub>CM</sub>	peak collector current	single pulse; t <sub>p</sub> ≤ 1 ms		-	-6	А
I <sub>B</sub>	base current			-	-500	mA
I <sub>BM</sub>	peak base current	single pulse; t <sub>p</sub> ≤ 1 ms		-	-1	А
P <sub>tot</sub>	total power dissipation		[1]	-	500	mW
			[2]	-	950	mW
			[3]	-	1.35	W
Tj	junction temperature			-	150	°C
T <sub>amb</sub>	ambient temperature			-55	150	°C
T <sub>stg</sub>	storage temperature			-65	150	°C

[1] Device mounted on an FR4 Printed-Circuit Board (PCB), single-sided copper, tin-plated and standard footprint.

[2] Device mounted on an FR4 PCB, single-sided copper, tin-plated, mounting pad for collector 1 cm<sup>2</sup>.

[3] Device mounted on an FR4 PCB, single-sided copper, tin-plated, mounting pad for collector 6 cm<sup>2</sup>.



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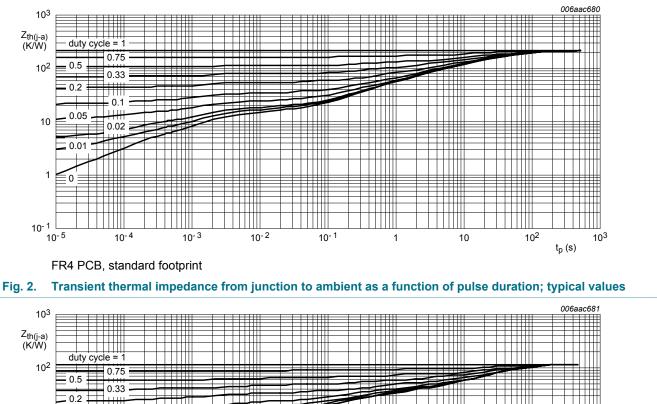
## 9. Thermal characteristics

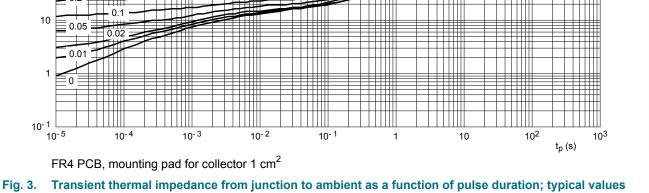
Table 6. Therr	nal characteristics						
Symbol	Parameter	Conditions		Min	Тур	Max	Unit
frc	thermal resistance	in free air	[1]	-	-	250	K/W
	from junction to ambient		[2]	-	-	132	K/W
			[3]	-	-	93	K/W

[1] Device mounted on an FR4 PCB, single-sided copper, tin-plated and standard footprint.

[2] Device mounted on an FR4 PCB, single-sided copper, tin-plated, mounting pad for collector 1 cm<sup>2</sup>.

[3] Device mounted on an FR4 PCB, single-sided copper, tin-plated, mounting pad for collector 6 cm<sup>2</sup>.



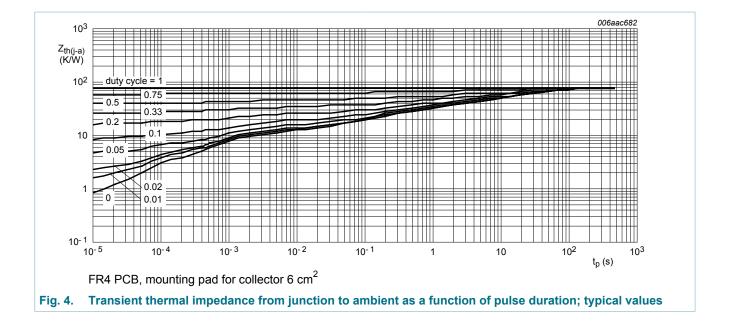


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## **10. Characteristics**

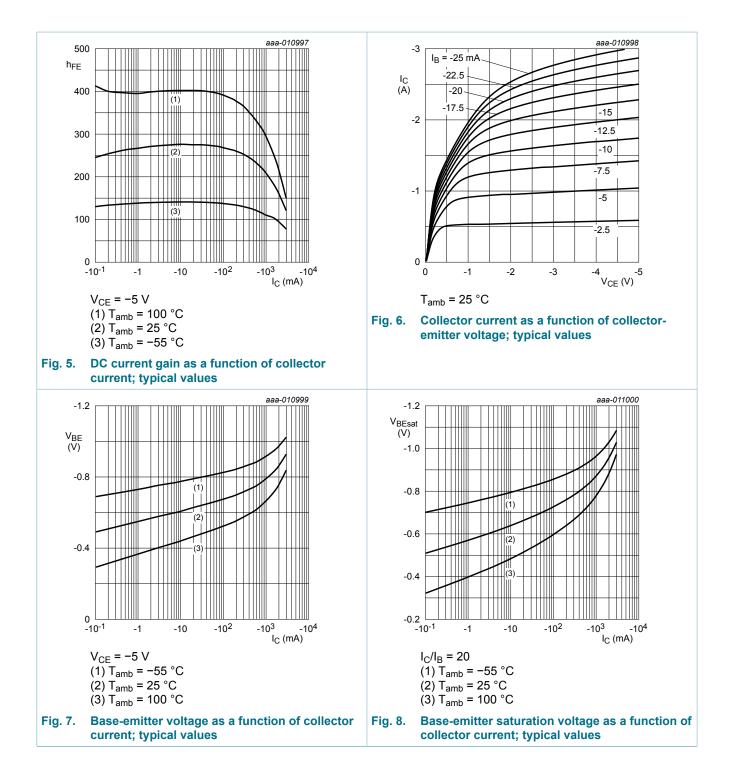
Symbol	Parameter	Conditions		Min	Тур	Max	Unit
I <sub>CBO</sub>	collector-base cut-off	$V_{CB}$ = -48 V; I <sub>E</sub> = 0 A; T <sub>amb</sub> = 25 °C		-	-	-100	nA
	current	V <sub>CB</sub> = -48 V; I <sub>E</sub> = 0 A; T <sub>j</sub> = 150 °C		-	-	-50	μA
I <sub>CES</sub>	collector-emitter cut-off current	$V_{CE}$ = -48 V; $V_{BE}$ = 0 V; $T_{amb}$ = 25 °C		-	-	-100	nA
I <sub>EBO</sub>	emitter-base cut-off current	$V_{EB}$ = -5 V; I <sub>C</sub> = 0 A; T <sub>amb</sub> = 25 °C		-	-	-100	nA
h <sub>FE</sub>	DC current gain	$V_{CE}$ = -5 V; I <sub>C</sub> = -50 mA; T <sub>amb</sub> = 25 °C		150	-	-	
		$V_{CE}$ = -5 V; I <sub>C</sub> = -500 mA; T <sub>amb</sub> = 25 °C		130	-	-	
		$V_{CE}$ = -5 V; I <sub>C</sub> = -1 A; T <sub>amb</sub> = 25 °C		120	-	-	
		$V_{CE}$ = -5 V; I <sub>C</sub> = -2 A; T <sub>amb</sub> = 25 °C	[1]	100	-	-	
		$V_{CE}$ = -5 V; I <sub>C</sub> = -3 A; T <sub>amb</sub> = 25 °C	[1]	80	-	-	
V <sub>CEsat</sub>	collector-emitter saturation voltage	$I_{C}$ = -500 mA; $I_{B}$ = -50 mA; $T_{amb}$ = 25 °C		-	-	-150	mV
		$I_{C}$ = -1 A; $I_{B}$ = -100 mA; $T_{amb}$ = 25 °C	[1]	-	-	-200	mV
		$I_{C}$ = -2 A; $I_{B}$ = -200 mA; $T_{amb}$ = 25 °C	[1]	-	-	-450	mV
		$I_C$ = -3 A; $I_B$ = -300 mA; $T_{amb}$ = 25 °C	[1]	-	-	-550	mV
R <sub>CEsat</sub>	collector-emitter saturation resistance	$I_{C}$ = -2 A; $I_{B}$ = -200 mA; $T_{amb}$ = 25 °C	[1]	-	-	225	mΩ
V <sub>BEsat</sub>	base-emitter saturation voltage	$I_{C}$ = -1 A; $I_{B}$ = -100 mA; $T_{amb}$ = 25 °C	[1]	-	-	-1.2	V
V <sub>BEon</sub>	base-emitter turn-on voltage	$V_{CE}$ = -5 V; $I_{C}$ = -1 A; $T_{amb}$ = 25 °C	[1]	-	-	-1.1	V
f <sub>T</sub>	transition frequency	$V_{CE}$ = -10 V; I <sub>C</sub> = -50 mA; f = 100 MHz; T <sub>amb</sub> = 25 °C		65	130	-	MHz
C <sub>c</sub>	collector capacitance	V <sub>CB</sub> = -10 V; I <sub>E</sub> = 0 A; i <sub>e</sub> = 0 A; f = 1 MHz; T <sub>amb</sub> = 25 °C		-	28	32	pF

[1] Pulse test:  $t_p \le 300 \ \mu s; \ \delta \le 0.02$ 

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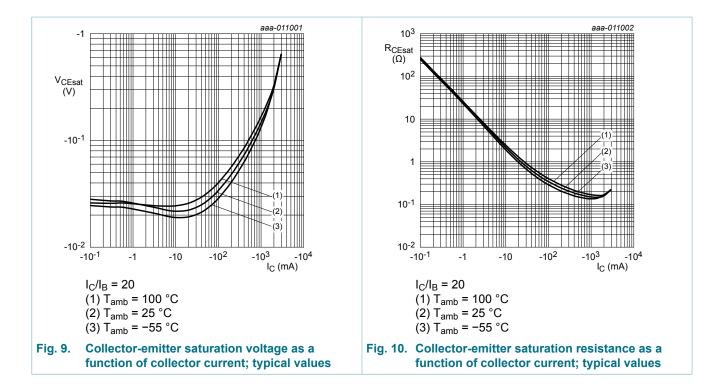
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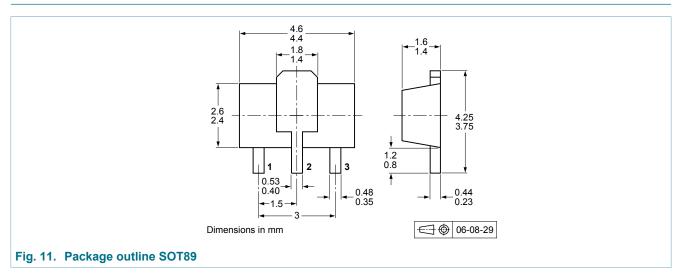


## **11. Test information**

#### **Quality information**

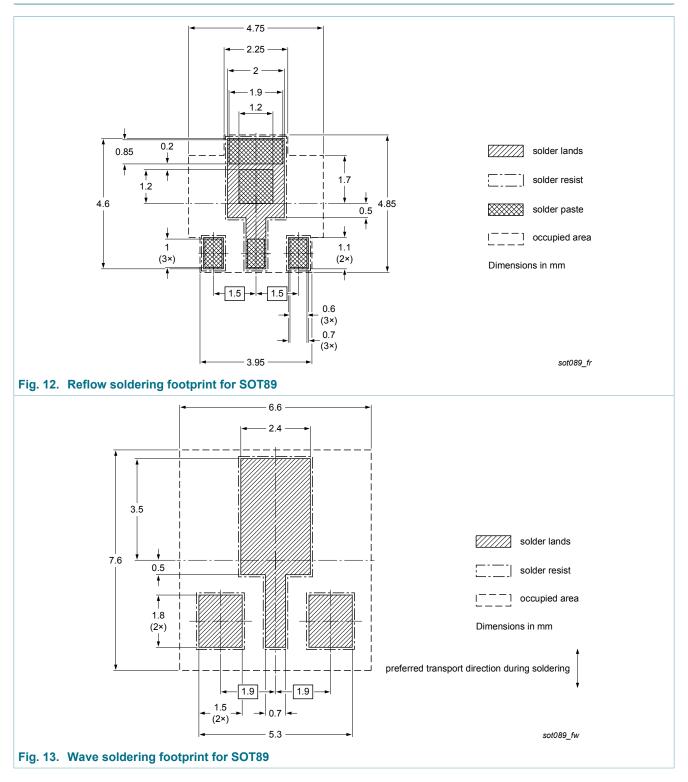
This product has been qualified in accordance with the Automotive Electronics Council (AEC) standard Q101 - *Stress test qualification for discrete semiconductors*, and is suitable for use in automotive applications.

## 12. Package outline



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## 13. Soldering



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## 14. Revision history

Table 8. Revision history						
Data sheet ID	Release date	Data sheet status	Change notice	Supersedes		
PBSS5360X v.1	20170703	Product data sheet	-	-		

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## 15. Legal information

#### **Data sheet status**

Document status [1][2]	Product status [3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

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